March 2020 Product data sheet

### 1. General description

The GAN063-650WSA is a 650 V, 50 m $\Omega$  Gallium Nitride (GaN) FET. It is a normally-off device that combines Nexperia's state-of-the-art high-voltage GaN HEMT and low-voltage silicon MOSFET technologies — offering superior reliability and performance.

#### 2. Features and benefits

- Ultra-low reverse recovery charge
- Simple gate drive (0 V to +10 V or 12 V)
- Robust gate oxide (±20 V capability)
- High gate threshold voltage (+4 V) for very good gate bounce immunity
- · Very low source-drain voltage in reverse conduction mode
- Transient over-voltage capability (800 V)

### 3. Applications

- · Hard and soft switching converters for industrial and datacom power
- · Bridgeless totempole PFC
- · PV and UPS inverters
- · Servo motor drives

#### 4. Quick reference data

#### Table 1. Quick reference data

Cumbal	Parameter	Conditions	Min	Tvn	Max	Unit
Symbol	Parameter	Conditions	IVIIII	Тур	IVIAX	Ullit
$V_{DS}$	drain-source voltage	-55 °C ≤ T <sub>j</sub> ≤ 175 °C	-	-	650	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	-	34.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	-	143	W
Tj	junction temperature		-55	-	175	°C
Static chara	acteristics					<u>'</u>
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	50	60	mΩ
Dynamic ch	aracteristics					'
$Q_{GD}$	gate-drain charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 400 V; V <sub>GS</sub> = 10 V;	-	4	-	nC
Q <sub>G(tot)</sub>	total gate charge	T <sub>j</sub> = 25 °C	-	15	-	nC
Source-drai	in diode					'
Q <sub>r</sub>	recovered charge	I <sub>S</sub> = 25 A; dI <sub>S</sub> /dt = -1000 A/μs; V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 400 V; <u>Fig. 14</u>	-	125	-	nC



## 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	S	source		
3	D	drain		
mb	S	mounting base; connected to source	TO-247 (SOT429)	G s aaa-028116

## 6. Ordering information

**Table 3. Ordering information** 

Type number	Package	Package						
	Name	Description	Version					
GAN063-650WSA	TO-247	plastic, single-ended through-hole package; 3 leads; 5.45 mm pitch; 20.45 mm x 15.6 mm x 4.95 mm body	SOT429					

## 7. Marking

Table 4. Marking codes

Type number	Marking code
GAN063-650WSA	GAN063-650WSA

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	-55 °C ≤ T <sub>j</sub> ≤ 175 °C	-	650	V
$V_{TDS}$	transient drain to source voltage	pulsed; $t_p = 1 \mu s$ ; $\delta_{factor} = 0.01$	-	800	V
V <sub>GS</sub>	gate-source voltage		-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	143	W
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	34.5	Α
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>	-	24.4	Α
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \text{ °C}$ ; Fig. 3	-	150	Α
T <sub>stg</sub>	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
$T_{sld(M)}$	peak soldering temperature		-	260	°C
Source-drai	n diode				'
Is	source current	T <sub>mb</sub> = 25 °C; V <sub>GS</sub> = 0 V	-	34.5	Α

Symbol	Parameter	Conditions	Min	Max	Unit
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 °C$	-	150	Α

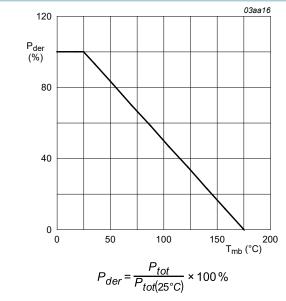
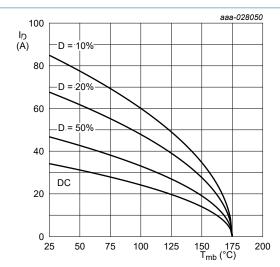
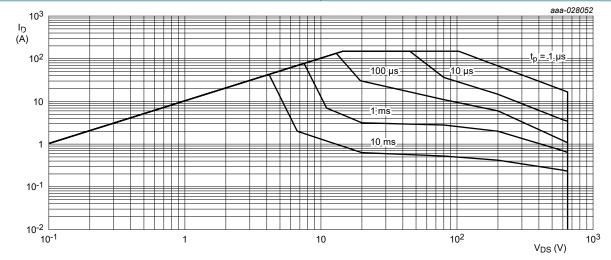


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



V<sub>GS</sub> ≥ 10 V; Pulse width ≤ 10 μs

Fig. 2. Drain current as a function of mounting base temperature



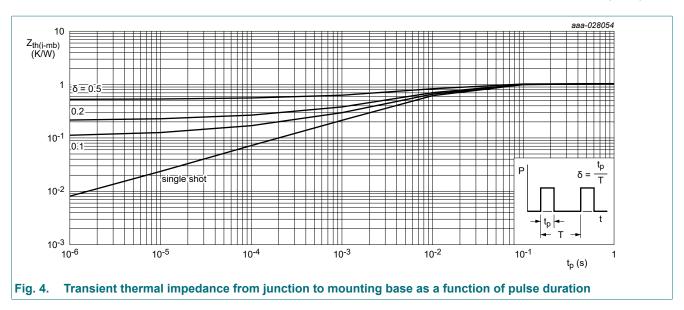
 $T_{mb}$  = 25 °C;  $I_{DM}$  is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 4	-	-	1.05	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in free air	-	-	40	K/W



### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>GS(th)</sub>	gate-source threshold	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	3.4	3.9	4.5	V
	voltage	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 175 °C; <u>Fig. 9</u>	2.2	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}; Fig. 9$	-	-	5.2	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 650 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	25	μΑ
		V <sub>DS</sub> = 650 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	25	-	μΑ
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	10	100	nA
		V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	10	100	nA
R <sub>DSon</sub>	drain-source on-state	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C}$	-	50	60	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 175 °C; Fig. 10	-	120	-	mΩ
$R_G$	gate resistance	f = 1 MHz	-	2.3	-	Ω
Dynamic ch	naracteristics				'	
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 400 V; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C	-	15	-	nC
Q <sub>GS</sub>	gate-source charge		-	6	-	nC
$Q_{GD}$	gate-drain charge		-	4	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 400 V; V <sub>GS</sub> = 0 V; f = 1 MHz;	-	1000	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	130	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	8	-	pF
C <sub>o(er)</sub>	effective output capacitance, energy related	$0 \text{ V} \le \text{ V}_{DS} \le 400 \text{ V}; \text{ V}_{GS} = 0 \text{ V};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. } 12$	-	190	-	pF
C <sub>o(tr)</sub>	effective output capacitance, time related	$0 \text{ V} \le \text{ V}_{DS} \le 400 \text{ V}; \text{ V}_{GS} = 0 \text{ V};$ $\text{T}_{j} = 25 \text{ °C}$	-	310	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = 400 \text{ V}; R_L = 16 \Omega; V_{GS} = 12 \text{ V};$	-	57	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 40 \Omega$	-	10	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	88	-	ns
t <sub>f</sub>	fall time		-	11	-	ns
Q <sub>oss</sub>	output charge	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 400 V	-	125	-	nC
Source-dra	ain diode		•			
$V_{SD}$	source-drain voltage	I <sub>S</sub> = 25 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <u>Fig. 13</u>	-	1.9	-	V
		I <sub>S</sub> = 12.5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	1.35	-	V
t <sub>rr</sub>	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -1000 \text{ A/}\mu\text{s};$ $V_{GS} = 0 \text{ V}; V_{DS} = 400 \text{ V}; Fig. 14$	-	54	-	ns
Q <sub>r</sub>	recovered charge		-	125	-	nC

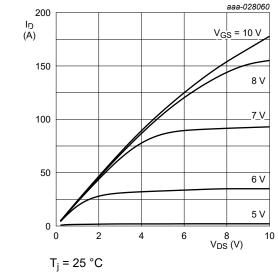


Fig. 5. Output characteristics; drain current as a function of drain-source voltage; typical values

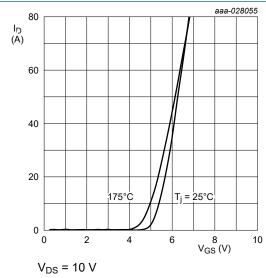


Fig. 7. Transfer characteristics; drain current as a function of gate-source voltage; typical values

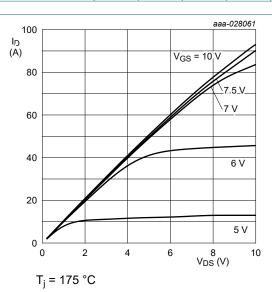


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

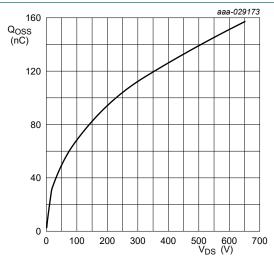


Fig. 8. Typical QOSS

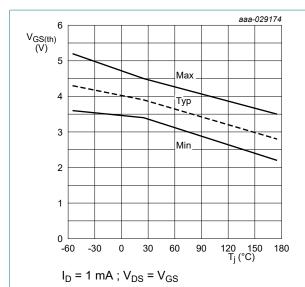


Fig. 9. Gate-source threshold voltage as a function of junction temperature

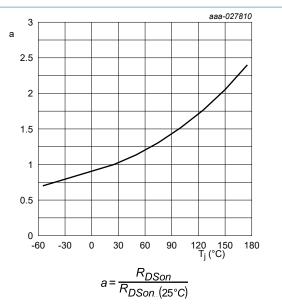


Fig. 10. Normalized drain-source on-state resistance factor as a function of junction temperature

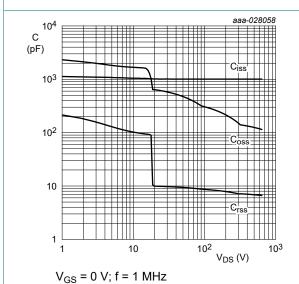


Fig. 11. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

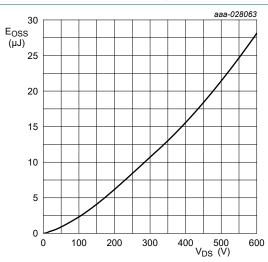


Fig. 12. Typical COSS Stored Energy

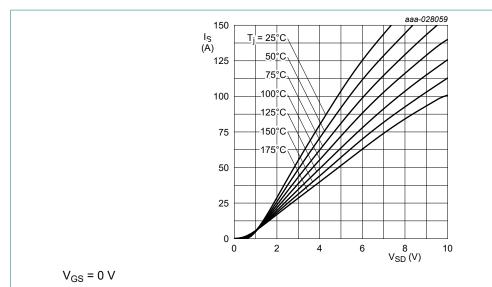
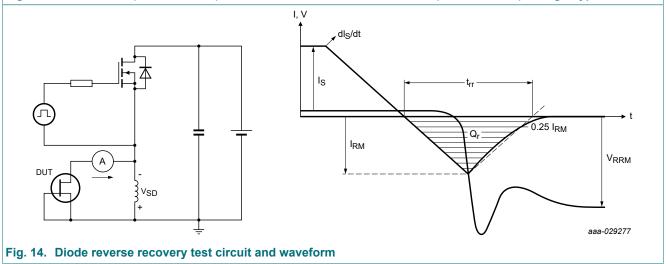


Fig. 13. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

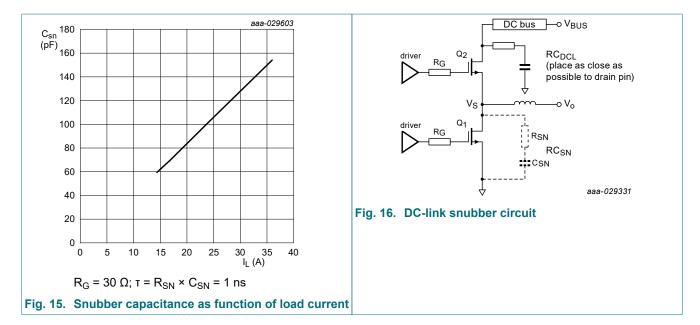


## 11. Application information

To achieve maximum efficiency and stability when switching high currents, a switching node RC snubber ( $R_{sn}$ ,  $C_{sn}$ ) is recommended. For  $I_L$  < 14 A, a switching-node snubber is not required.

 $C_{\text{SN}}$  is taken from the graph.

 $R_{SN}$  should be selected to achieve a time constant of 1 ns; e.g. if  $C_{SN}$  = 100 pF,  $R_{SN}$  = 1 ns / 100 pF = 10  $\Omega.$ 





**Note:** A DC-link snubber is recommended in all cases. Optimal is 20 nF in series with 4  $\Omega$ , most easily achieved with parallel combination 10 nF and 8  $\Omega$ . This snubber lowers the Q factor of any resonance in the bus. That resonance will act as a load on the high gain amplifier that is the GaN FET and can lead to instability. For very high current, an RC snubber is recommended for the switching node. This will increase switching loss, so this is only recommended at high power levels where the losses are a very small percentage of the total power.

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## 12. Package outline

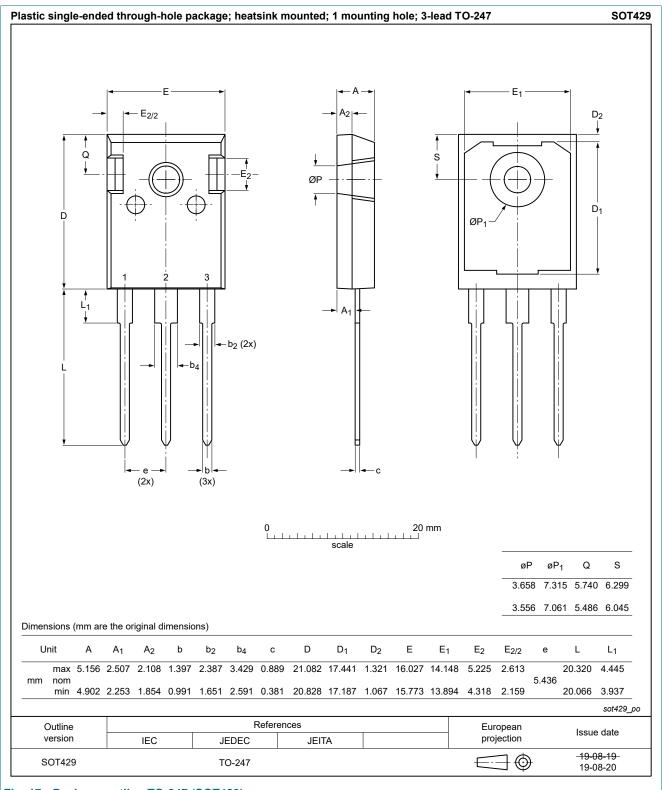


Fig. 17. Package outline TO-247 (SOT429)

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